

BD707/709/711 BD708/712

COMPLEMENTARY SILICON POWER TRANSISTORS

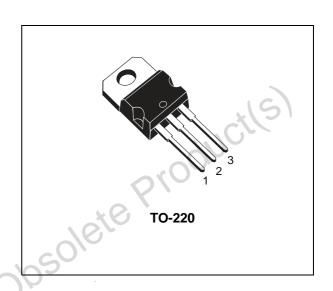
■ COMPLEMENTARY PNP - NPN DEVICES

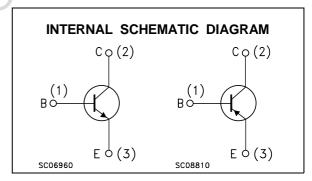
APPLICATION

 LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

DESCRIPTION

The BD707, BD709 and BD711 are silicon Epitaxial-Base NPN power transistors in Jedec TO-220 plastic package. They are intented for use in power linear and switching applications. The BD707 and BD711 complementary PNP types are BD708 and BD712 respectively.





ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | | Value | | | |
|------------------|-------------------------------------------------|-----|------------|-------|-------|----|
| | | NPN | BD707 | BD709 | BD711 | |
| | | PNP | BD708 | | BD712 | |
| V _{CBO} | Collector-Base Voltage (I _E = 0) | | 60 | 80 | 100 | V |
| V _{CER} | Collector-Emitter Voltage (V _{BE} = 0) | | 60 | 80 | 100 | V |
| V_{CEO} | Collector-Emitter Voltage (I _B = 0) | | 60 | 80 | 100 | V |
| V_{EBO} | Emitter-Base Voltage (I _C = 0) | | | 5 | | V |
| Ic | Collector Current | | | Α | | |
| I _{CM} | Collector Peak Current | | | Α | | |
| Ι _Β | Base Current | | 5 | | | Α |
| P _{tot} | Total Dissipation at T _c ≤ 25 °C | | | W | | |
| T _{stg} | Storage Temperature | | -65 to 150 | | | °C |
| Tj | Max. Operating Junction Temperature | | | °C | | |

For PNP types voltage and current values are negative

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THERMAL DATA

| R _{thj-case} | Thermal Resistance Junction-case | Max | 1.67 | °C/W |
|-----------------------|-------------------------------------|-----|------|------|
| R _{thj-case} | Thermal Resistance Junction-ambient | Max | 70 | °C/W |

ELECTRICAL CHARACTERISTICS ($T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

| Symbol | Parameter | Test C | Conditions | Min. | Тур. | Max. | Unit |
|-------------------------|-----------------------------------------------------------------|---------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------|-----------------|--------------|-------------------|----------------------|
| Ісво | Collector Cut-off Current (I _E = 0) | for BD707/708 for BD709 for BD711/712 T _{case} = 150 °C for BD707/708 | $V_{CB} = 60 \text{ V}$ $V_{CB} = 80 \text{ V}$ $V_{CB} = 100 \text{ V}$ $V_{CB} = 60 \text{ V}$ | | | 100 100 100 | μΑ μΑ μΑ mA |
| | | for BD709 for BD711/712 | $V_{CB} = 80 \text{ V}$ $V_{CB} = 100 \text{ V}$ | | | 1 | mA mA |
| I _{CEO} | Collector Cut-off Current (I _B = 0) | for BD707/708 for BD709 for BD711/712 | V _{CE} = 30 V V _{CE} = 40 V V _{CE} = 50 V | | 9/1 | 100 100 100 | mA mA mA |
| I _{EBO} | Emitter Cut-off Current (I _C = 0) | V _{EB} = 5 V | | 6/ | | 1 | mA |
| V _{CEO(sus)} * | Collector-Emitter Sustaining Voltage (I _B = 0) | I _C = 100 mA for BD707/708 for BD709 for BD711/712 | colete | 60 80 100 | | | < < < |
| V _{CE(sat)} * | Collector-Emitter Saturation Voltage | I _C = 4 A | I _B = 0.4 A | | | 1 | V |
| V _{CEK} * | Knee Voltage | I _C = 3 A | I _B = ** | | | 0.4 | V |
| V _{BE} * | Base-Emitter Voltage | I _C = 4 A | V _{CE} = 4 V | | | 1.5 | V |
| h _{FE} * | DC Current Gain | I _C = 0.5 A I _C = 2 A | V _{CE} = 2 V V _{CE} = 2 V for BD707/708 for BD709 | 40 30 30 | 120 | 400 | |
| \(() | ic Pro | I _C = 4 A I _C = 10 A | V _{CE} = 4 V V _{CE} = 4 V for BD707/708 for BD709 for BD711/712 | 15 5 | 10 8 8 | 150 | |
| Cf _T O | Transition frequency | I _C = 300 mA | V _{CE} = 3 V | 3 | | | MHz |

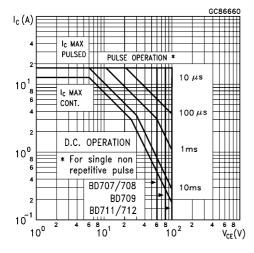
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^{*} Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

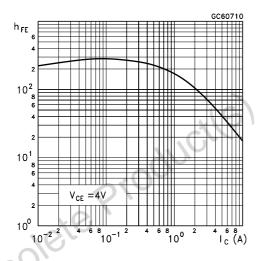
** Value for which Ic = 3.3 A at V_{CE} = 2V.

For PNP types voltage and current values are negative.

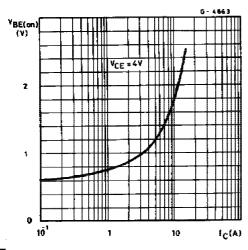
Safe Operating Areas



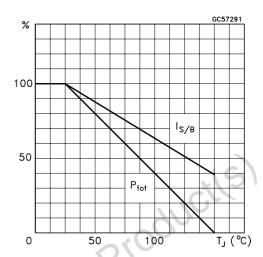
DC Current Gain(NPN type)



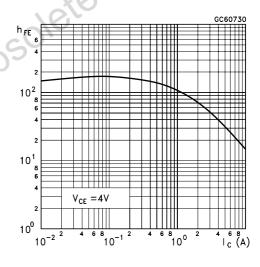
DC Transconductance(NPN type)



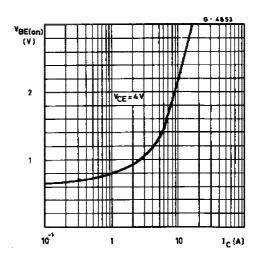
Derating Curve



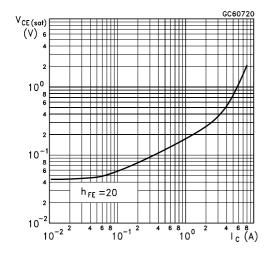
DC Current Gain(PNP type)



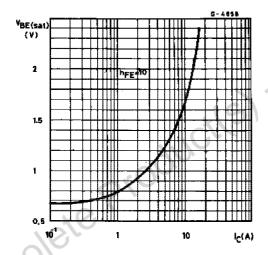
DC Transconductance(PNP type)



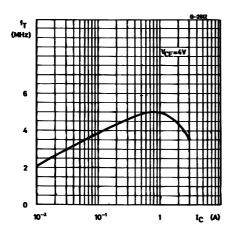
Collector-Emitter Saturation Voltage (NPN type)



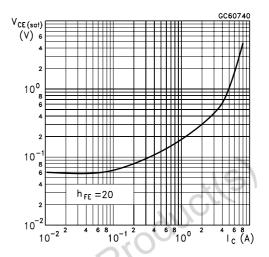
Base-Emitter Saturation Voltage (NPN type)



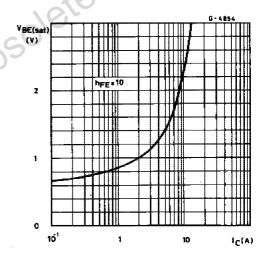
Transition Frequency (NPN type)



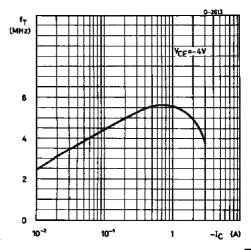
Collector-Emitter Saturation Voltage (PNP type)



Base-Emitter Saturation Voltage (PNP type)

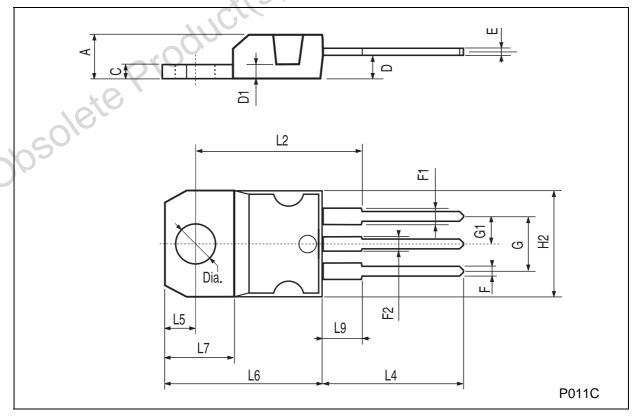


Transition Frequency (PNP type)



TO-220 MECHANICAL DATA

| DIM. | mm | | | inch | | | |
|--------|-------|------|-------|-------|-------|-------|--|
| DIIVI. | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | |
| Α | 4.40 | | 4.60 | 0.173 | | 0.181 | |
| С | 1.23 | | 1.32 | 0.048 | | 0.051 | |
| D | 2.40 | | 2.72 | 0.094 | | 0.107 | |
| D1 | | 1.27 | | | 0.050 | | |
| E | 0.49 | | 0.70 | 0.019 | | 0.027 | |
| F | 0.61 | | 0.88 | 0.024 | | 0.034 | |
| F1 | 1.14 | | 1.70 | 0.044 | | 0.067 | |
| F2 | 1.14 | | 1.70 | 0.044 | | 0.067 | |
| G | 4.95 | | 5.15 | 0.194 | AV | 0.203 | |
| G1 | 2.4 | | 2.7 | 0.094 | -400 | 0.106 | |
| H2 | 10.0 | | 10.40 | 0.393 | | 0.409 | |
| L2 | | 16.4 | | v. Q. | 0.645 | | |
| L4 | 13.0 | | 14.0 | 0.511 | | 0.551 | |
| L5 | 2.65 | | 2.95 | 0.104 | | 0.116 | |
| L6 | 15.25 | | 15.75 | 0.600 | | 0.620 | |
| L7 | 6.2 | | 6.6 | 0.244 | | 0.260 | |
| L9 | 3.5 | | 3.93 | 0.137 | | 0.154 | |
| DIA. | 3.75 | | 3.85 | 0.147 | | 0.151 | |



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